# DMC96102

### Silicon NPN epitaxial planar type

#### For digital circuits

DMC56102 in SSMini5 type package

#### Features

- $\bullet$  Low collector-emitter saturation voltage  $V_{CE(\text{sat})}$
- Contributes to miniaturization of sets, reduction of component count.
- Eco-friendly Halogen-free package

#### Basic Part Number

Dual DRC2124E (Common emitter)

#### Packaging

DMC961020R Embossed type (Thermo-compression sealing): 8000 pcs / reel (standard)

#### Absolute Maximum Ratings $T_a = 25^{\circ}C$

Electrical Characteristics  $T_a = 25^{\circ}C \pm 3^{\circ}C$ 

Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	V <sub>CBO</sub>	50	V
Collector-emitter voltage (Base open)	V <sub>CEO</sub>	50	V
Collector current	I <sub>C</sub>	100	mA
Total power dissipation	P <sub>T</sub>	125	mW
Junction temperature	Tj	150	°C
Storage temperature	T <sub>stg</sub>	-55 to +150	°C

#### Package

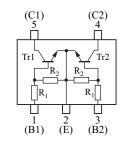
Code
SSMini5-F4-B
Package dimension clicks here.→

#### • Pin Name

- 1: Base (Tr1) 4: Collector (Tr2)
- 2: Emitter (Common) 5: Collector (Tr1)
- 3: Base (Tr2)

Marking Symbol: F5

#### Internal Connection



Resistance value	R <sub>1</sub>	22	kΩ
	R <sub>2</sub>	22	

#### Conditions Parameter Symbol Min Тур Max Unit V Collector-base voltage (Emitter open) V<sub>CBO</sub> $I_{C} = 10 \ \mu A, I_{E} = 0$ 50 Collector-emitter voltage (Base open) $I_{\rm C} = 2 \, {\rm mA}, I_{\rm B} = 0$ 50 V V<sub>CEO</sub> Collector-base cutoff current (Emitter open) $V_{CB} = 50 \text{ V}, I_E = 0$ 0.1 I<sub>CBO</sub> μΑ Collector-emitter cutoff current (Base open) $V_{CE} = 50 \text{ V}, I_B = 0$ 0.5 I<sub>CEO</sub> μA Emitter-base cutoff current (Collector open) $V_{EB} = 6 V, I_C = 0$ 0.2 mА $I_{\text{EBO}}$ Forward current transfer ratio $h_{FE}$ $V_{CE} = 10 \text{ V}, I_C = 5 \text{ mA}$ 60 Collector-emitter saturation voltage V<sub>CE(sat)</sub> $I_{\rm C} = 10 \text{ mA}, I_{\rm B} = 0.5 \text{ mA}$ 0.25 V $V_{CE} = 0.2 \text{ V}, I_C = 5 \text{ mA}$ V Input voltage (ON) V<sub>I(on)</sub> 2.6 Input voltage (OFF) $V_{CE} = 5 \text{ V}, I_C = 100 \text{ }\mu\text{A}$ V 0.8 V<sub>I(off)</sub> +30%Input resistance $R_1$ -30%22 kΩ Resistance ratio $R_1 / R_2$ 0.8 1.0 1.2

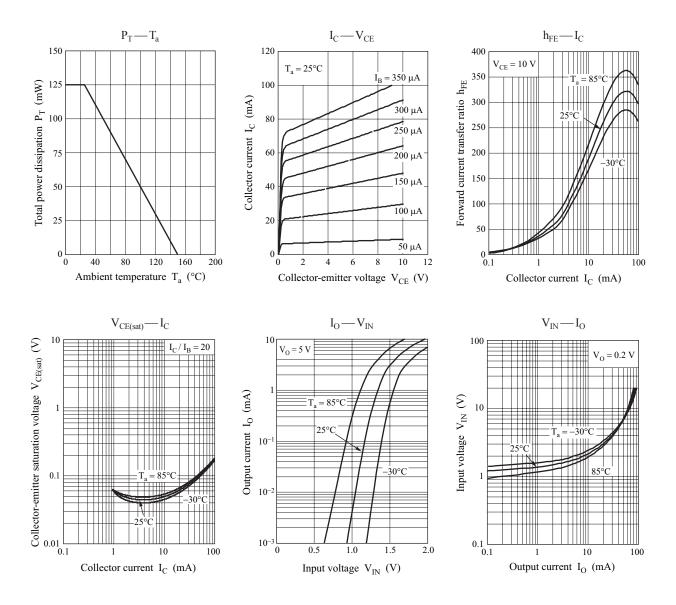
Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

### Publication date: February 2012

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### **Panasonic**



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